# OPTICALLY COUPLED BILATERAL SWITCH LIGHT ACTIVATED ZERO VOLTAGE CROSSING TRIAC





### APPROVALS

• UL recognised, File No. E91231 Package System " TT "

# 'X'SPECIFICATIONAPPROVALS

- VDE 0884 in 3 available lead form : -
  - STD
  - G form
  - SMD approved to CECC 00802

### DESCRIPTION

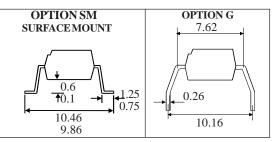
The MOC303\_Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a monolithic silicon detector performing the functions of a zero crossing bilateral triac mounted in a standard 6 pin dual-in-line package.

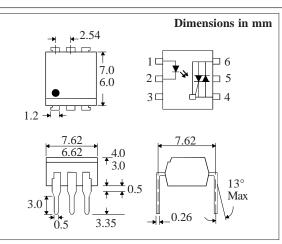
### FEATURES

- Options :-10mm lead spread - add G after part no. Surface mount - add SM after part no. Tape&reel - add SMT&R after part no.
- High Isolation Voltage  $(5.3 k V_{RMS}, 7.5 k V_{PK})$
- Zero Voltage Crossing
- 250V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

## APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances
- Printers





# ABSOLUTE MAXIMUM RATINGS (25 °C unless otherwise noted)

Storage Temperature	-55°C-+150°C
Operating Temperature	-40°C - +100°C
Lead Soldering Temperature(1.6mm from case for 10 seconds	$260^{\circ}C$

## INPUTDIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	120mW
(derate linearly 1.41mW/°C above 25°	<sup>0</sup> C)

## **OUTPUT PHOTO TRIAC**

Off-State Output Terminal Voltage	250V		
Forward Current (Peak)	1A		
Power Dissipation	150mW		
(derate linearly 1.76mW/°C above 25°C)			

## **POWER DISSIPATION**

Total Power Dissipation \_\_\_\_\_ 250mW (derate linearly 2.94mW/<sup>0</sup>C above 25<sup>0</sup>C)

### ISOCOM COMPONENTS 2004 LTD

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	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITION
Input	Forward Voltage ( $V_F$ ) Reverse Current ( $I_R$ )		1.2	1.5 10	V μA	$I_F = 20mA$ $V_R = 6V$
Output	Peak Off-state Current ( $I_{DRM}$ ) Peak Blocking Voltage ( $V_{DRM}$ ) On-state Voltage ( $V_{TM}$ )	250		500 3.0	nA V V	$V_{DRM} = 250V \text{ (note 1)}$ $I_{DRM} = 500nA$ $I_{TM} = 100mA \text{ (peak)}$
	Critical rate of rise of off-state Voltage ( dv/dt )	600	1500		V/µs	
Coupled	Input Current to Trigger (I <sub>FT</sub> )(note 2) MOC3030 MOC3031 MOC3032 MOC3033			30 15 10 5	mA mA mA mA	$V_{TM} = 3V (note 2)$
	Holding Current , either direction ( $I_H$ ) Input to Output Isolation Voltage $V_{ISO}$	5300 7500	400		μΑ V <sub>RMS</sub> V <sub>PK</sub>	See note 3 See note 3
Zero Crossing Charact- -eristic	Inhibit Voltage (V <sub>IH</sub> )			20	V	I <sub>F</sub> =Rated I <sub>FT</sub> MT1-MT2 Voltage above which device
	Leakage in Inhibited State ( ${\rm I}_{\rm S}$ )			500	μΑ	will not trigger $I_F = Rated I_{FT}$ $V_{DRM} = 250V$ off-state

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ Unless otherwise noted)

Note 1. Test voltage must be applied within dv/dt rating. Note 2. Guaranteed to trigger at an I<sub>F</sub> value less than or equal to max. I<sub>FT</sub>, recommended I<sub>F</sub> lies between Rated I<sub>FT</sub> and absolute max. I<sub>F</sub>. Note 3. Measured with input leads shorted together and output leads shorted together.